

MBRX120 THRU MBRX140

SCHOTTKY BARRIER RECTIFIERS

FEATURES

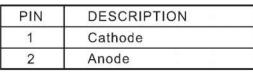
- Metal silicon junction, majority carrier conduction
- Guarding for overvoltage protection
- Low power loss, high efficiency
- High current capability
- low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

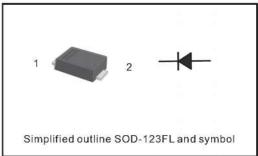
MECHANICAL DATA

- Case: SOD-123FL
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight:15mg 0.00048oz

Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.





Parameter	Symbols	MBRX120	MBRX130	MBRX140	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	30	40	V
Maximum RMS voltage	V _{rms}	14	21	28	V
Maximum DC Blocking Voltage	V _{DG}	20	30	40	V
MaximumAverage Forward Rectified Current 0.375″ (9.5 mm) Lead Length at T∟= 90°C	_{F(AV)}		А		
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed On Rated Load (JEDEC method) at TL = 70°C	I _{FSM}		А		
Maximum Instantaneous Forward Voltage at 1 A Maximum Instantaneous Forward Voltage at 3.1 A	V _F	0.45 0.75	0.55 0.875	0.6 0.9	V
Maximum Instantaneous Reverse Current at TA = 25°C Rated DC Reverse Voltage TA = 100°C	۱ _R	1 10			mA
Typical Junction Capacitance	Cj	110			pF
Storage and Operating Junction Temperature Range	Tj, T _{stg}	-55 ~ +125			°C



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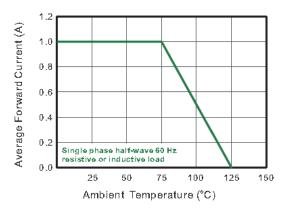
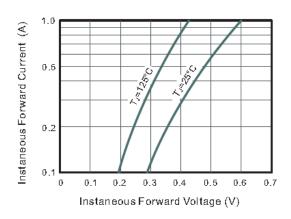


Fig.3 Typical Forward Characteristic



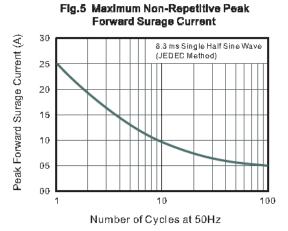


Fig.2 Typical Reverse Characteristics

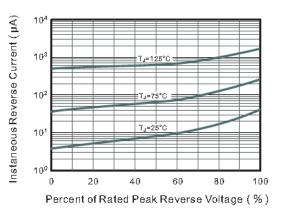
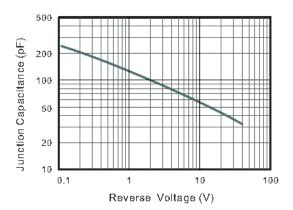
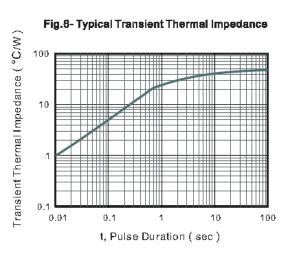


Fig.4 Typical Junction Capacitance



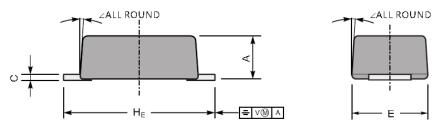


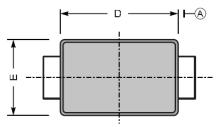


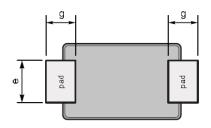
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PACKAGE OUTLINE

Plastic surface mounted package; 2 leads SOD-123FL







Top View



UNIT		А	С	D	E	e	g	HE	2
mm	max	1.1	0.20	2.9	1.9	1.1	0.9	3.8	7°
	min	0.9	0.12	2.6	1.7	0.8	0.7	3.5	
mil	max	43	7.9	114	75	43	35	150	(
	min	35	4.7	102	67	31	28	138	

The recommended mounting pad size

